Complementary Silicon Power Transistors

The MJ15003 and MJ15004 are PowerBase power transistors designed for high power audio, disk head positioners and other linear applications.

- High Safe Operating Area (100% Tested) 250 W @ 50 V
- For Low Distortion Complementary Designs
- High DC Current Gain —
 hFF = 25 (Min) @ I_C = 5 Adc

MJ15003* PNP MJ15004*

*Motorola Preferred Device

20 AMPERE
POWER TRANSISTORS
COMPLEMENTARY
SILICON
140 VOLTS
250 WATTS



CASE 1-07 TO-204AA (TO-3)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	140	Vdc
Collector-Base Voltage	V _{CBO}	140	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector Current — Continuous	l _C	20	Adc
Base Current — Continuous	lΒ	5	Adc
Emitter Current — Continuous	lΕ	25	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	250 1.43	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	0.70	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/16" from Case for ≤ 10 seconds	TL	265	°C

Preferred devices are Motorola recommended choices for future use and best overall value.



MJ15003 MJ15004

*ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				-
Collector Emitter Sustaining Voltage (1) (I _C = 200 mAdc, I _B = 0)	V _{CEO(sus)}	140	_	Vdc
Collector Cutoff Current (V _{CE} = 140 Vdc, V _{BE(off)} = 1.5 Vdc) (V _{CE} = 140 Vdc, V _{BE(off)} = 1.5 Vdc, T _C = 150°C)	ICEX	_	100 2	μAdc mAdc
Collector Cutoff Current (V _{CE} = 140 Vdc, I _B = 0)	ICEO	_	250	μAdc
Emitter Cutoff Current (VEB = 5 Vdc, IC = 0)	I _{EBO}	_	100	μAdc
SECOND BREAKDOWN				-
Second Breakdown Collector Current with Base Forward Baised (VCE = 50 Vdc, t = 1 s (non repetitive)) (VCE = 100 Vdc, t = 1 s (non repetitive))	I _{S/b}	5 1	_	Adc
ON CHARACTERISTICS				
DC Current Gain (IC = 5 Adc, VCE = 2 Vdc)	hFE	25	150	
Collector Emitter Saturation Voltage (I _C = 5 Adc, I _B = 0.5 Adc)	V _{CE(sat)}	_	1	Vdc
Base Emitter On Voltage (I _C = 5 Adc, V _{CE} = 2 Vdc)	V _{BE(on)}	_	2	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain — Bandwidth Product (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f _{test} = 0.5 MHz)	fT	2	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	cop	_	1000	pF

⁽¹⁾ Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2%.

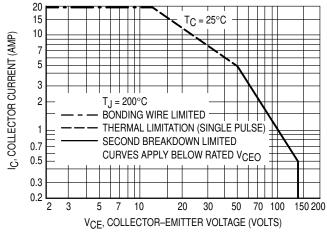
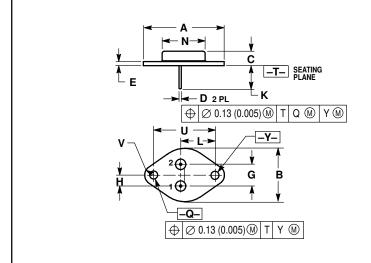


Figure 1. Active-Region Safe Operating Area

There are two limitations on the powerhandling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{\text{C}} - V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on $T_{J(pk)} = 200 \,^{\circ}\text{C}$; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В	-	1.050		26.67	
C	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
Е	0.055	0.070	1.40	1.77	
G	0.430 BSC		10.92 BSC		
Н	0.215	BSC	5.46	.46 BSC	
K	0.440	0.480	11.18	12.19	
L	0.665 BSC		16.89 BSC		
N		0.830		21.08	
ø	0.151	0.165	3.84	4.19	
J	1.187 BSC		30.15 BSC		
٧	0.131	0.188	3 33	4 77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

CASE 1-07 TO-204AA (TO-3) ISSUE Z

MJ15003 MJ15004

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